

Title (en)

PROCESS FOR PREPARING A SiC PRECURSOR MATERIAL

Title (de)

VERFAHREN ZUR HERSTELLUNG EINES SiC-PRECURSORMATERIALS

Title (fr)

PROCÉDÉ DE PRÉPARATION D'UN MATERIAU PRÉCURSEUR DE SiC

Publication

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Application

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Abstract (en)

[origin: WO2021023761A1] The invention relates to a process for preparing a SiC precursor material suitable for producing silicon carbide-containing materials, in particular silicon carbide, specifically in high-energy processes.

IPC 8 full level

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CPC (source: EP)

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Citation (search report)

See references of WO 2021023761A1

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